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#### **Description (Continued)**

The TISP4xxxM3BJ range consists of nineteen voltage variants to meet various maximum system voltage levels (58 V to 320 V). They are guaranteed to voltage limit and withstand the listed international lightning surges in both polarities. These medium (M) current protection devices are in a plastic package SMBJ (JEDEC DO-214AA with J-bend leads) and supplied in embossed tape reel pack. For alternative voltage and holding current values, consult the factory. For higher rated impulse currents in the SMB package, the 100 A 10/1000 TISP4xxxH3BJ series is available.

#### Absolute Maximum Ratings, TA = 25 °C (Unless Otherwise Noted)

Rating	Symbol	Value	Unit
'4070		±58	
'4080		±65	
'4095		±75	
'4115		±90	
'4125		±100	
'4145		±120	
'4165		±135	1
'4180		±145	
'4200		±155	
Repetitive peak off-state voltage, (see Note 1) '4220	$V_{DRM}$	±160	V
4240	2	±180	
'4250		±190	
'4265		±200	
'4290		±220	
·4300		±230	
'4350		±275	
'4360		±290	
'4395		±320	
'4400		±300	
Non-repetitive peak on-state pulse current (see Notes 2, 3 and 4)			
2/10 μs (GR-1089-CORE, 2/10 μs voltage wave shape)		300	
8/20 µs (IEC 61000-4-5, combination wave generator, 1.2/50 voltage, 8/20 current)		220	
10/160 μs (FCC Part 68, 10/160 μs voltage wave shape)		120	
5/200 µs (VDE 0433, 10/700 µs voltage wave shape)	I <sub>TSP</sub>	110	_
0.2/310 μs (I3124, 0.5/700 μs voltage wave shape)		100	Α
5/310 μ (ITU-T K.20/21/45, K.44 10/700 μs voltage wave shape)		100	
5/310 μs (FTZ R12, 10/700 μs voltage wave shape)		100	
10/560 μs (FCC Part 68, 10/560 μs voltage wave shape)		75	
10/1000 µs (GR-1089-CORE, 10/1000 µs voltage wave shape)		50	
Non-repetitive peak on-state current (see Notes 2, 3 and 5)			
20 ms (50 Hz) full sine wave		30	
16.7 ms (60 Hz) full sine wave	I <sub>TSM</sub>	32	Α
1000 s 50 Hz/60 Hz a.c.		2.1	
Initial rate of rise of on-state current, Exponential current ramp, Maximum ramp value < 100 A	di <sub>T</sub> /dt	300	A/µs
Junction temperature	TJ	-40 to +150	°C
Storage temperature range	T <sub>stg</sub>	-65 to +150	°C

NOTES: 1. See Applications Information and Figure 11 for voltage values at lower temperatures.

- 2. Initially, the TISP4xxxM3BJ must be in thermal equilibrium with  $T_J$  = 25 °C.
- 3. The surge may be repeated after the TISP4xxxM3BJ returns to its initial conditions.
- ${\it 4. \ \, See \ \, Applications \ \, Information \ \, and \ \, Figure \ \, 12 \ \, for \ \, current \ \, ratings \ \, at \ \, other \ \, temperatures.}}$
- 5. EIA/JESD51-2 environment and EIA/JESD51-3 PCB with standard footprint dimensions connected with 5 A rated printed wiring track widths. See Figure 9 for the current ratings at other durations. Derate current values at -0.61 %/°C for ambient temperatures above 25 °C.

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### Electrical Characteristics, T<sub>A</sub> = 25 °C (Unless Otherwise Noted)

	Parameter	Test Conditions		Min	Тур	Max	Unit
lon.	Repetitive peak off-	$V_D = V_{DRM}$	T <sub>A</sub> = 25 °C			±5	μΑ
I <sub>DRM</sub>	state current	VD - VDRM	$T_A = 85  ^{\circ}C$			±10	μΛ
		'4070			±70		
			'4080			±80	
			'4095			±95	
			'4115			±115	
			'4125			±125	
			'4145			±145	
			'4165			±165	
			'4180			±180	
			'4200			±200	
V <sub>(BO)</sub>	Breakover voltage	$dv/dt = \pm 250 \text{ V/ms},  R_{SOURCE} = 300 \Omega$	'4220			±220	V
			'4240			±240	
			'4250			±250	
			'4265			±265	
			'4290			±290	
			'4300			±300	
			<sup>4350</sup>			±350	
			'4360			±360	
			·4395			±395	
			'4400			±400	
			'4070			±78	
			'4080			±88	
			'4095			±102	
			'4115			±122	
			'4125			±132	
			'4145			±151	
			'4165			±171	
			'4180			±186	
		dv/dt ≤ ±1000 V/μs, Linear voltage ramp,	'4200			±207	
V <sub>(BO)</sub>	Impulse breakover	Maximum ramp value = ±500 V	'4220			±227	V
(20)	voltage	di/dt = ±20 A/μs, Linear current ramp,	'4240			±247	
		Maximum ramp value = ±10 A	'4250			±257	
			'4265			±272	
			'4290			±298	
			'4300			±308	
			'4350			±359	
			'4360			±370	
			'4395			±405	
			'4400			±410	
I <sub>(BO)</sub>	Breakover current	$dv/dt = \pm 250 \text{ V/ms},  R_{SOURCE} = 300 \Omega$		±0.15		±0.6	Α
V <sub>T</sub>	On-state voltage	$I_T = \pm 5 \text{ A}, t_W = 100 \mu \text{s}$				±3	V
lΗ	Holding current	$I_T = \pm 5 \text{ A, di/dt} = +/-30 \text{ mA/ms}$		±0.15		±0.35	Α
dv/dt	Critical rate of rise of off-state voltage	Linear voltage ramp, Maximum ramp value < 0.85V DRM		±5			kV/μs
I <sub>D</sub>	Off-state current	$V_D = \pm 50 \text{ V}$	T <sub>A</sub> = 85 °C			±10	μΑ

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### Electrical Characteristics, T<sub>A</sub> = 25 °C (Unless Otherwise Noted)

	Parameter	Test Conditions		Min	Тур	Max	Unit
		$f = 1 \text{ MHz}, V_d = 1 \text{ V rms}, V_D = 0$	4070 thru '4115		83	100	
			'4125 thru '4220		62	74	
			'4240 thru '4400		50	60	
		$f = 1 \text{ MHz}, V_d = 1 \text{ V rms}, V_D = -1 \text{ V}$	'4070 thru '4115		78	94	
			'4125 thru '4220		56	67	
			'4240 thru '4400		45	54	
	O# state same sitemas	$f = 1 \text{ MHz}, V_d = 1 \text{ V rms}, V_D = -2 \text{ V}$	'4070 thru '4115		72	87	
C <sub>off</sub>	Off-state capacitance		'4125 thru '4220		52	62	pF
			'4240 thru '4400		42	50	
		$f = 1 \text{ MHz}, V_d = 1 \text{ V rms}, V_D = -50 \text{ V}$	'4070 thru '4115		36	44	
			'4125 thru '4220		26	31	
			'4240 thru '4400		19	22	
		$f = 1 \text{ MHz}, V_d = 1 \text{ V rms}, V_D = -100 \text{ V}$	'4125 thru '4220		21	25	
		(see Note 6)	'4240 thru '4400		15	18	

6: To avoid possible voltage clipping, the '4125 is tested with  $V_D = -98 \text{ V}$ .

#### **Thermal Characteristics**

Parameter		Test Conditions		Тур	Max	Unit
$R_{\theta JA}$ Junction to free air thermal resistance	EIA/JESD51-3 PCB, $I_T = I_{TSM(1000)}$ , $T_A = 25$ °C, (see Note 7)			115	°C/W	
THUJA	difficient to free all thermal resistance	265 mm x 210 mm populated line card, 4-layer PCB, I <sub>T</sub> = I <sub>TSM(1000)</sub> , T <sub>A</sub> = 25 °C		52		0,,,,

NOTE 7: EIA/JESD51-2 environment and PCB has standard footprint dimensions connected with 5 A rated printed wiring track widths.

#### **Parameter Measurement Information**

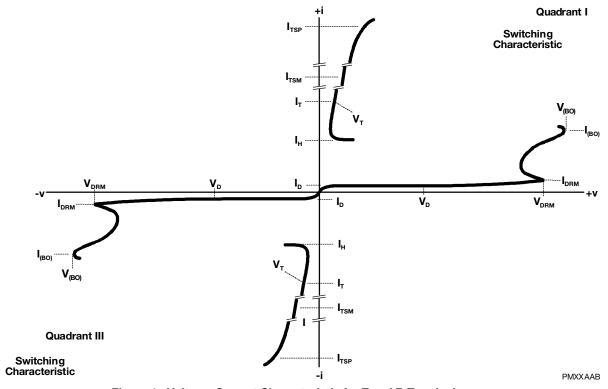


Figure 1. Voltage-Current Characteristic for T and R Terminals All Measurements are Referenced to the R Terminal

#### **Typical Characteristics**

# **OFF-STATE CURRENT** JUNCTION TEMPERATURE

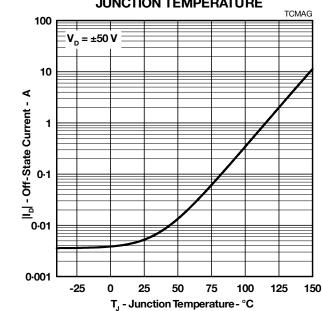
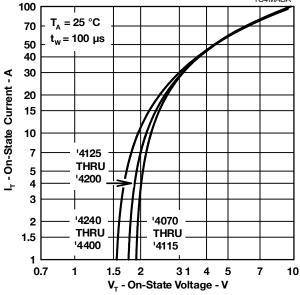


Figure 2.

#### **ON-STATE CURRENT**

**ON-STATE VOLTAGE** 

TC4MACA



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Figure 4.

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### **NORMALIZED BREAKOVER VOLTAGE**

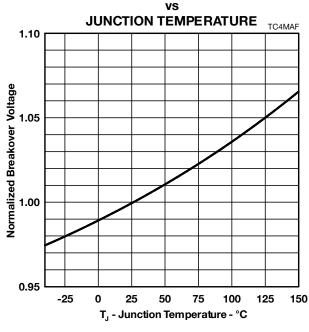
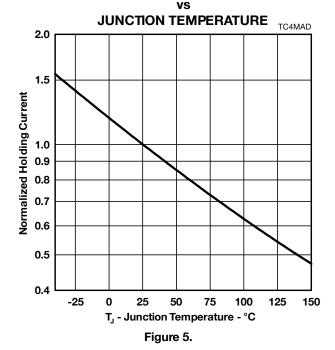


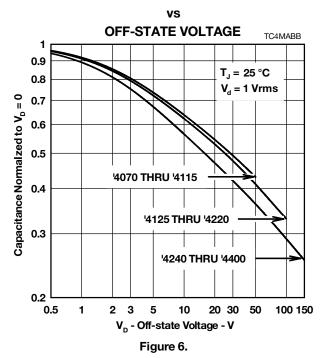
Figure 3.

# NORMALIZED HOLDING CURRENT



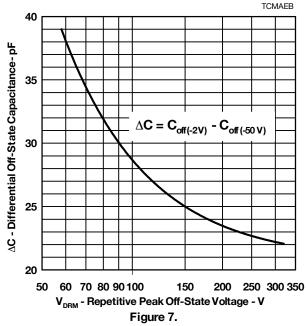
#### **Typical Characteristics**

#### NORMALIZED CAPACITANCE

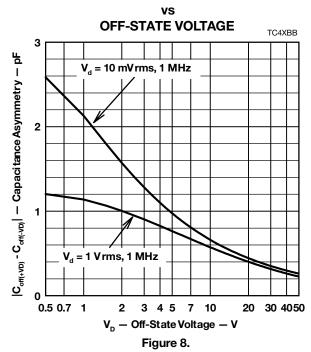


# DIFFERENTIAL OFF-STATE CAPACITANCE vs

### RATED REPETITIVE PEAK OFF-STATE VOLTAGE



#### TYPICAL CAPACITANCE ASYMMETRY



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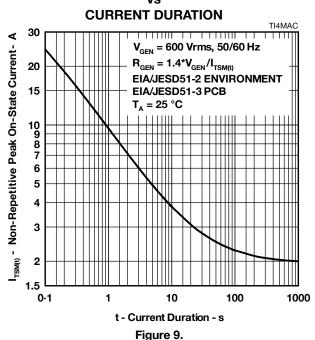
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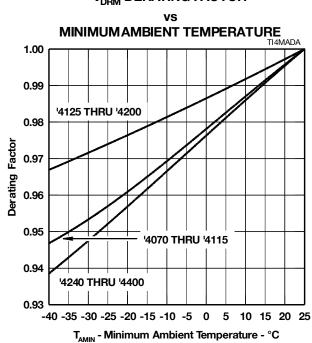
#### **Rating and Thermal Information**

# NON-REPETITIVE PEAK ON-STATE CURRENT



### THERMAL IMPEDANCE **POWER DURATION** TI4MAE 150 Z<sub>0.4(t)</sub> - Transient Thermal Impedance - °C/W 100 90 80 70 60 50 40 30 20 15 10 9 8 7 6 **EIA/JESD51-2 ENVIRONMENT** EIA/JESD51-3 PCB $T_A = 25 \, ^{\circ}C$ 5 0.1 100 1000 t - Power Duration - s Figure 10.

### **V<sub>DRM</sub> DERATING FACTOR**



vs **AMBIENT TEMPERATURE** TC4MAA 400 **BELLCORE 2/10** 300 250 IEC 1.2/50, 8/20 200 Current - A 150 FCC 10/160 120 Impulse 100 ITU-T 10/700 90 80 70 FCC 10/560 60 50 **BELLCORE 10/1000** -40 -30 -20 -10 0 10 20 30 40 50 60 70 80 T<sub>A</sub> - Ambient Temperature - °C

Figure 12.

IMPULSE RATING

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Figure 11.

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#### **APPLICATIONS INFORMATION**

#### **Deployment**

These devices are two terminal overvoltage protectors. They may be used either singly to limit the voltage between two conductors (Figure 13) or in multiples to limit the voltage at several points in a circuit (Figure 14).

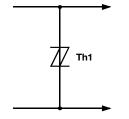


Figure 13. Two Point Protection

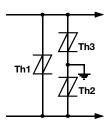


Figure 14. Multi-Point Protection

In Figure 13, protector Th1 limits the maximum voltage between the two conductors to  $\pm V(BO)$ . This configuration is normally used to protect circuits without a ground reference, such as modems. In Figure 14, protectors Th2 and Th3 limit the maximum voltage between each conductor and ground to the  $\pm V(BO)$  of the individual protector. Protector Th1 limits the maximum voltage between the two conductors to its  $\pm V(BO)$  value. If the equipment being protected has all its vulnerable components connected between the conductors and ground, then protector Th1 is not required.

#### **Impulse Testing**

To verify the withstand capability and safety of the equipment, standards require that the equipment is tested with various impulse wave forms. The table below shows some common values.

Standard	Peak Voltage Setting V	Voltage Wave Shape μs	Peak Current Value A	Current Wave Shape μs	TISP4XXXM3 25 °C Rating A	Series Resistance $\Omega$
GR-1089-CORE	2500	2/10	500	2/10	300	11
GH-1009-CORL	1000	10/1000	100	10/1000	50	"
	1500	10/160	200	10/160	120	2x5.6
FCC Part 68	800	10/560	100	10/560	75	3
(March 1998)	1500	9/720 †	37.5	5/320 †	100	0
	1000	9/720 †	25	5/320 †	100	0
l3124	1500	0.5/700	37.5	0.2/310	100	0
ITU-T K.20/K.21	1500 4000	10/700	37.5 100	5/310	100	0

<sup>†</sup> FCC Part 68 terminology for the waveforms produced by the ITU-T recommendation K.21 10/700 impulse generator

If the impulse generator current exceeds the protector's current rating, then a series resistance can be used to reduce the current to the protector's rated value to prevent possible failure. The required value of series resistance for a given waveform is given by the following calculations. First, the minimum total circuit impedance is found by dividing the impulse generator's peak voltage by the protector's rated current. The impulse generator's fictive impedance (generator's peak voltage divided by peak short circuit current) is then subtracted from the minimum total circuit impedance to give the required value of series resistance.

For the FCC Part 68 10/560 waveform, the following values result. The minimum total circuit impedance is  $800/75 = 10.7~\Omega$  and the generator's fictive impedance is  $800/100 = 8~\Omega$ . This gives a minimum series resistance value of  $10.7 - 8 = 2.7~\Omega$ . After allowing for tolerance, a  $3~\Omega \pm 10\%$  resistor would be suitable. The 10/160 waveform needs a standard resistor value of  $5.6~\Omega$  per conductor. These would be R1a and R1b in Figure 16 and Figure 17. FCC Part 68 allows the equipment to be non-operational after the 10/160 (conductor to ground) and 10/560 (inter-conductor) impulses. The series resistor value may be reduced to zero to pass FCC Part 68 in a non-operational mode, e.g. Figure 15. For this type of design, the series fuse must open before the TISP4xxxM3 fails. For Figure 15, the maximum fuse  $i^2t$  is  $2.3~A^2s$ . In some cases, the equipment will require verification over a temperature range. By using the rated waveform values from Figure 12, the appropriate series resistor value can be calculated for ambient temperatures in the range of  $-40~^{\circ}C$  to  $85~^{\circ}C$ .

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#### **AC Power Testing**

The protector can withstand currents applied for times not exceeding those shown in Figure 9. Currents that exceed these times must be terminated or reduced to avoid protector failure. Fuses, PTC (Positive Temperature Coefficient) thermistors and fusible resistors are overcurrent protection devices which can be used to reduce the current flow. Protective fuses may range from a few hundred milliamperes to one ampere. In some cases, it may be necessary to add some extra series resistance to prevent the fuse opening during impulse testing. The current versus time characteristic of the overcurrent protector must be below the line shown in Figure 9. In some cases, there may be a further time limit imposed by the test standard (e.g. UL 1459 wiring simulator failure).

#### Capacitance

The protector characteristic off-state capacitance values are given for d.c. bias voltage, VD, values of 0, -1 V, -2 V and -50 V. Where possible values are also given for -100 V. Values for other voltages may be calculated by multiplying the VD = 0 capacitance value by the factor given in Figure 6. Up to 10 MHz, the capacitance is essentially independent of frequency. Above 10 MHz, the effective capacitance is strongly dependent on connection inductance. In many applications, such as Figure 16 and Figure 18, the typical conductor bias voltages will be about -2 V and -50 V. Figure 7 shows the differential (line unbalance) capacitance caused by biasing one protector at -2 V and the other at -50 V.

Figure 8 shows the typical capacitance asymmetry; the difference between the capacitance measured with a positive value of VD and the capacitance value when the polarity of VD is reversed. Capacitance asymmetry is an important parameter in ADSL systems where the protector often has no d.c. bias and the signal level is in the region of ±10 V.

#### **Normal System Voltage Levels**

The protector should not clip or limit the voltages that occur in normal system operation. For unusual conditions, such as ringing without the line connected, some degree of clipping is permissible. Under this condition, about 10 V of clipping is normally possible without activating the ring trip circuit.

Figure 11 allows the calculation of the protector VDRM value at temperatures below 25 °C. The calculated value should not be less than the maximum normal system voltages. The TISP4265M3BJ, with a VDRM of 200 V, can be used for the protection of ring generators producing 100 V rms of ring on a battery voltage of -58 V (Th2 and Th3 in Figure 18). The peak ring voltage will be 58 + 1.414\*100 = 199.4 V. However, this is the open circuit voltage and the connection of the line and its equipment will reduce the peak voltage. In the extreme case of an unconnected line, clipping the peak voltage to 190 V should not activate the ring trip. This level of clipping would occur at the temperature when the VDRM has reduced to 190/200 = 0.95 of its 25 °C value. Figure 11 shows that this condition will occur at an ambient temperature of -28 °C. In this example, the TISP4265M3BJ will allow normal equipment operation provided that the minimum expected ambient temperature does not fall below -28 °C.

#### **JESD51 Thermal Measurement Method**

To standardize thermal measurements, the EIA (Electronic Industries Alliance) has created the JESD51 standard. Part 2 of the standard (JESD51-2, 1995) describes the test environment. This is a 0.0283 m<sup>3</sup> (1 ft<sup>3</sup>) cube which contains the test PCB (Printed Circuit Board) horizontally mounted at the center. Part 3 of the standard (JESD51-3, 1996) defines two test PCBs for surface mount components; one for packages smaller than 27 mm on a side and the other for packages up to 48 mm. The SMBJ measurements used the smaller 76.2 mm x 114.3 mm (3.0 " x 4.5 ") PCB. The JESD51-3 PCBs are designed to have low effective thermal conductivity (high thermal resistance) and represent a worst case condition. The PCBs used in the majority of applications will achieve lower values of thermal resistance, and can dissipate higher power levels than indicated by the JESD51 values.

#### **Typical Circuits**

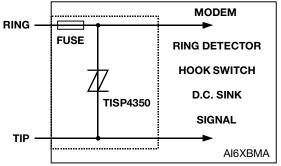


Figure 15. Modem Inter-Wire Protection

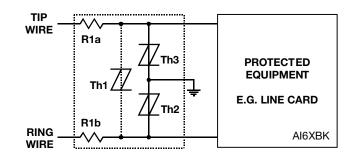


Figure 16. PROTECTION MODULE

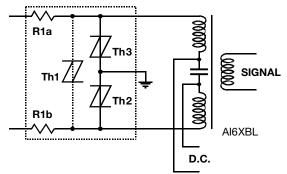


Figure 17. ISDN Protection

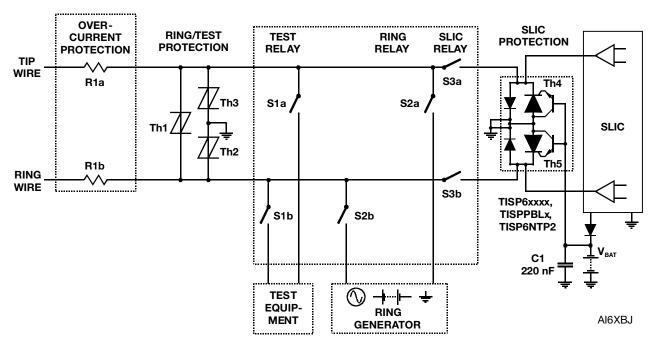


Figure 18. Line Card Ring/Test Protection

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#### **Device Symbolization Code**

Devices will be coded as below. As the device parameters are symmetrical, terminal 1 is not identified.

Device	Symbolization
Device	Code
TISP4070M3BJ	4070M3
TISP4080M3BJ	4080M3
TISP4095M3BJ	4095M3
TISP4115M3BJ	4115M3
TISP4125M3BJ	4125M3
TISP4145M3BJ	4145M3
TISP4165M3BJ	4165M3
TISP4180M3BJ	4180M3
TISP4200M3BJ	4200M3
TISP4220M3BJ	4220M3
TISP4240M3BJ	4240M3
TISP4250M3BJ	4250M3
TISP4265M3BJ	4265M3
TISP4290M3BJ	4290M3
TISP4300M3BJ	4300M3
TISP4350M3BJ	4350M3
TISP4360M3BJ	4360M3
TISP4395M3BJ	4395M3
TISP4400M3BJ	4400M3

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